

**HC540 OCTAL BUS BUFFER INVERTING (3-STATE)**  
**HC541 OCTAL BUS BUFFER (3-STATE)**

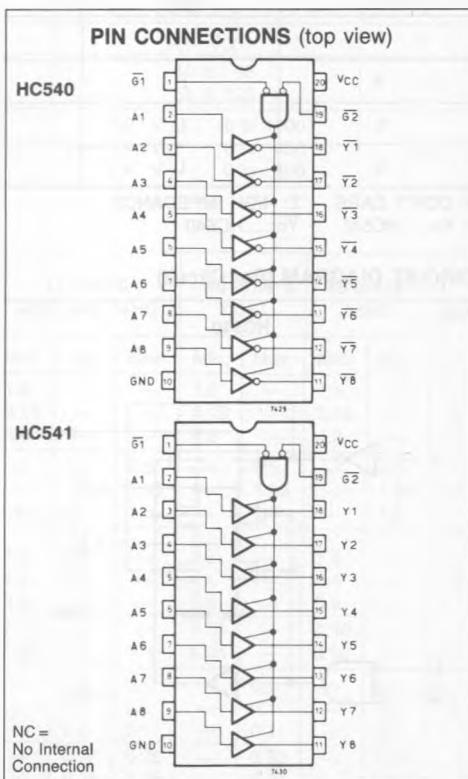
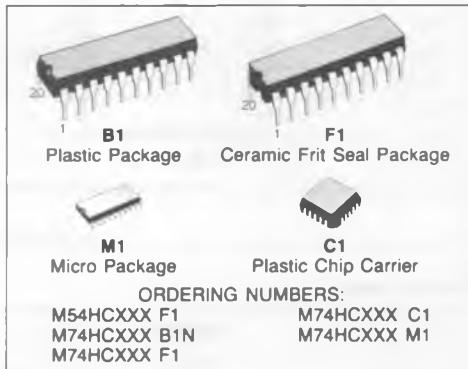
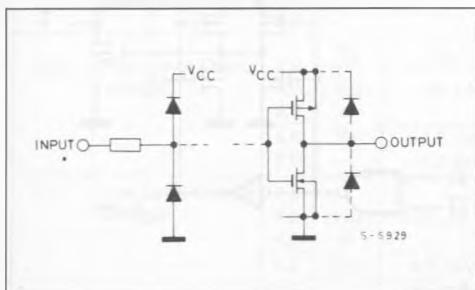
- HIGH SPEED  
 $t_{PD} = 11 \text{ ns (TYP.)}$  at  $V_{CC} = 5\text{V}$
- LOW POWER DISSIPATION  
 $I_{CC} = 4 \mu\text{A}$  (MAX.) at  $T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY  
 $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (MIN.)
- OUTPUT DRIVE CAPABILITY  
 15 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE  
 $|I_{OH}| = |I_{OL}| = 6 \text{ mA (MIN.)}$
- BALANCED PROPAGATION DELAYS  
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE  
 $V_{CC}$  (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE  
 WITH 54/74LS540/541

**DESCRIPTION**

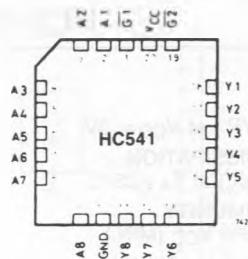
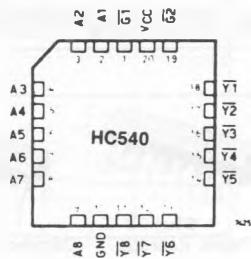
The M54/74HC540/541 are high speed CMOS OCTAL BUS BUFFERS (3-STATE) fabricated in silicon gate C<sup>2</sup>MOS technology. They have the same high speed performance of LSTTL combined with true CMOS low power consumption. The M54/74HC540 is an inverting buffer and the M54/74HC541 is a non-inverting buffer. The 3-STATE control gate operates as a two-input AND such that if either G1 or G2 are high, all eight outputs are in the high-impedance state.

In order to enhance PC board layout, the 'HC540 and 'HC541 offers a pinout having inputs and outputs on opposite sides of the package.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

**INPUT AND OUTPUT EQUIVALENT CIRCUIT**


## CHIP CARRIER



## TRUTH TABLE

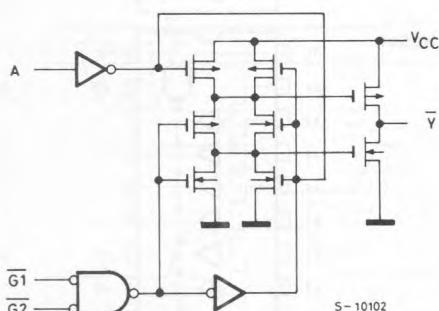
INPUTS			OUTPUT	
$\bar{G}_1$	$\bar{G}_2$	$A_n$	$Y_n^*$	$\bar{Y}_n^*$
H	X	X	Z	Z
X	H	X	Z	Z
L	L	H	L	L
L	L	L	L	H

X: DON'T CARE Z: HIGH IMPEDANCE

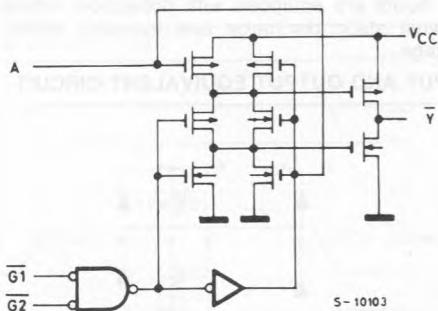
\*:  $Y_n \dots HC541$        $\bar{Y}_n \dots HC540$ 

## CIRCUIT DIAGRAM (Per Circuit)

HC540



HC541



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to 7	V
$V_I$	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
$V_O$	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	$\pm 20$	mA
$I_{OK}$	DC Output Diode Current	$\pm 20$	mA
$I_o$	DC Output Source Sink Current Per Output Pin	$\pm 35$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current	$\pm 70$	mA
$P_D$	Power Dissipation	500 (*)	mW
Tstg	Storage Temperature	-65 to 150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(\*) 500 mW:  $\equiv 65^\circ\text{C}$  derate to 300 mW by 10 mW/°C:  $65^\circ\text{C}$  to  $85^\circ\text{C}$ .

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	2 to 6	V
$V_I$	Input Voltage	0 to $V_{CC}$	V
$V_O$	Output Voltage	0 to $V_{CC}$	V
$T_A$	Operating Temperature 74HC Series 54HC Series	-40 to 85 -55 to 125	°C
$t_r, t_f$	Input Rise and Fall Time	$V_{CC} \left\{ \begin{array}{l} 2 \text{ V} \\ 4.5 \text{ V} \\ 6 \text{ V} \end{array} \right. \quad \begin{array}{l} 0 \text{ to } 1000 \\ 0 \text{ to } 500 \\ 0 \text{ to } 400 \end{array}$	ns

## DC SPECIFICATIONS

Symbol	Parameter	$V_{CC}$	Test Condition	$T_A = 25^\circ\text{C}$ 54HC and 74HC			$-40 \text{ to } 85^\circ\text{C}$ 74HC		$-55 \text{ to } 125^\circ\text{C}$ 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
$V_{IH}$	High Level Input Voltage	2.0		1.5	—	—	1.5	—	1.5	—	V
		4.5		3.15	—	—	3.15	—	3.15	—	
		6.0		4.2	—	—	4.2	—	4.2	—	
$V_{IL}$	Low Level Input Voltage	2.0		—	—	0.5	—	0.5	—	0.5	V
		4.5		—	—	1.35	—	1.35	—	1.35	
		6.0		—	—	1.8	—	1.8	—	1.8	
$V_{OH}$	High Level Output Voltage	2.0		$V_I$	$I_o$	1.9	2.0	—	1.9	—	V
		4.5		$V_{IH}$ or $V_{IL}$	-20 $\mu\text{A}$	4.4	4.5	—	4.4	—	
		6.0			5.9	6.0	—	5.9	—	5.9	
		4.5			-4.0 mA	4.18	4.31	—	4.13	—	
		6.0			-5.2 mA	5.68	5.8	—	5.63	—	
$V_{OL}$	Low Level Output Voltage	2.0		$V_{IH}$ or $V_{IL}$	20 $\mu\text{A}$	—	0.0	0.1	—	0.1	V
		4.5			—	0.0	0.1	—	0.1	—	
		6.0			—	0.0	0.1	—	0.1	—	
		4.5			4.0 mA	—	0.17	0.26	—	0.33	—
		6.0			5.2 mA	—	0.18	0.26	—	0.33	—

## DC SPECIFICATIONS (Continued)

Symbol	Parameter	V <sub>CC</sub>	Test Condition	T <sub>A</sub> = 25°C 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
I <sub>I</sub>	Input Leakage Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND	—	—	±0.1	—	±1.0	—	±1.0	µA
I <sub>OZ</sub>	3-State Output Off-State Current	6.0	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND	—	—	±0.5	—	±5.0	—	±10	µA
I <sub>CC</sub>	Quiescent Supply Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND	—	—	4	—	40	—	80	µA

AC ELECTRICAL CHARACTERISTICS (C<sub>L</sub> = 50pF, Input t<sub>r</sub> = t<sub>f</sub> = 6ns)

Symbol	Parameter	V <sub>CC</sub>	Test Condition	T <sub>A</sub> = 25°C 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t <sub>T LH</sub> t <sub>T HL</sub>	Output Transition Time	2.0		—	25	60	—	75	—	90	ns
		4.5		—	7	12	—	15	—	18	
		6.0		—	6	10	—	13	—	15	
t <sub>P LH</sub> t <sub>P H L</sub>	Propagation Delay Time	2.0	HC540	—	52	105	—	130	—	160	ns
		4.5		—	13	21	—	26	—	32	
		6.0		—	11	18	—	22	—	27	
t <sub>P LH</sub> t <sub>P H L</sub>	Propagation Delay Time	2.0	HC541	—	56	15	—	145	—	135	ns
		4.5		—	14	23	—	29	—	35	
		6.0		—	12	20	—	25	—	30	
t <sub>P LZ</sub> t <sub>P H Z</sub>	3-State Output Enable	2.0	R <sub>L</sub> = 1KΩ	—	72	145	—	180	—	220	ns
		4.5		—	18	29	—	36	—	44	
		6.0		—	15	25	—	31	—	38	
t <sub>P LZ</sub> t <sub>P H Z</sub>	3-State Output Disable Time	2.0	R <sub>L</sub> = 1KΩ	—	88	160	—	200	—	240	ns
		4.5		—	22	32	—	40	—	48	
		6.0		—	19	27	—	34	—	41	
C <sub>IN</sub>	Input Capacitance			—	5	10	—	10	—	10	pF
C <sub>OUT</sub>	Output Capacitance			—	10	—	—	—	—	—	pF
C <sub>PD</sub> (1)	Power Dissipation Capacitance		HC540	—	33	—	—	—	—	—	pF
				—	36	—	—	—	—	—	

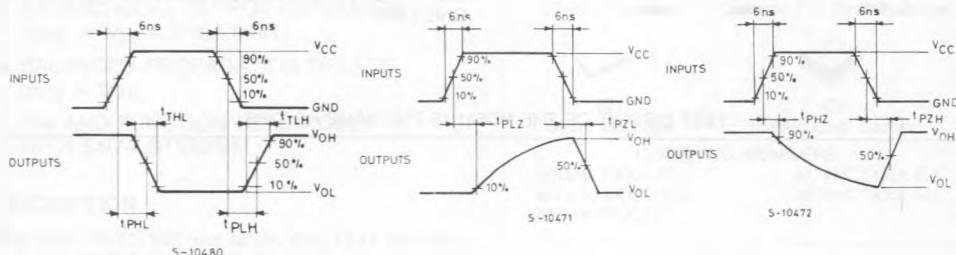
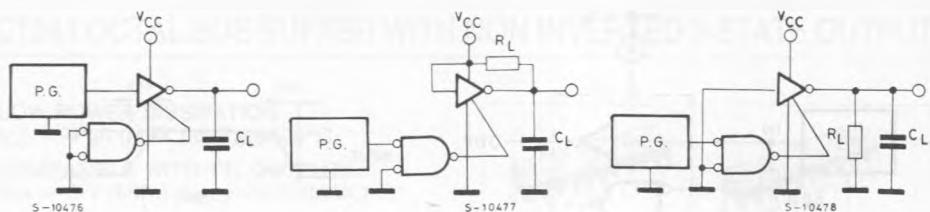
Note (1) C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the following equation.

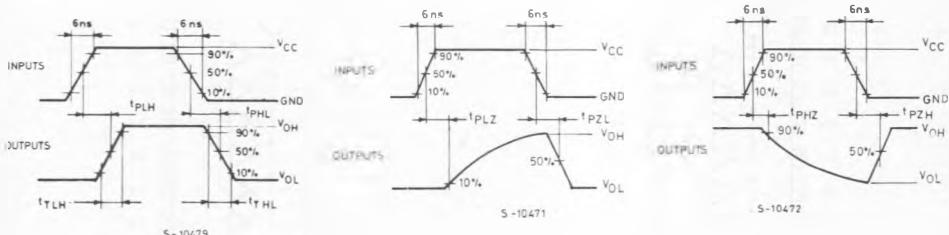
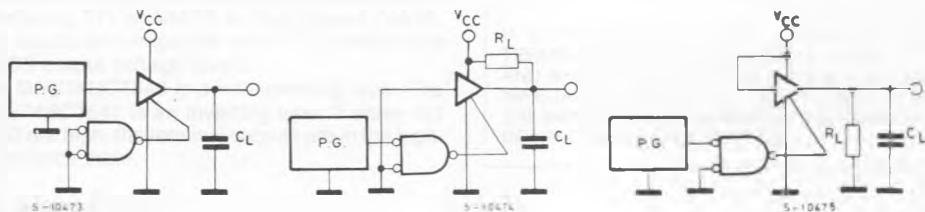
$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per Gate)}$$

## SWITCHING CHARACTERISTICS TEST CIRCUIT AND WAVEFORM

## HC540

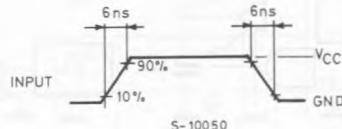
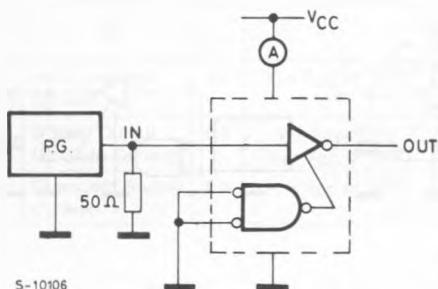


## HC541



TEST CIRCUIT I<sub>CC</sub> (Opr.)

HC540



THE OTHER INPUTS ARE CONNECTED V<sub>CC</sub> LINE OR GND LINE.

TEST CIRCUIT OF THE HC541 IS THE SAME AS THIS